



# PIMP32-Q

50 V, 500 mA PNP/PNP Resistor-Equipped double Transistor (RET); R1 = 2.2 k $\Omega$ , R2 = 10 k $\Omega$

16 February 2022

Product data sheet

## 1. General description

PNP/PNP Resistor-Equipped double Transistor (RET) in a small SOT457 (SC-74) Surface-Mounted Device (SMD) plastic package.

NPN/NPN complement: PIMN32-Q

NPN/PNP complement: PIMC32-Q

## 2. Features and benefits

- 500 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs
- Qualified according to AEC-Q101 and recommended for use in automotive applications

## 3. Applications

- Digital applications
- Cost-saving alternative to BC807-Q series in digital applications
- Control of IC inputs
- Switching loads

## 4. Quick reference data

Table 1. Quick reference data

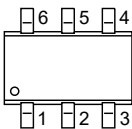
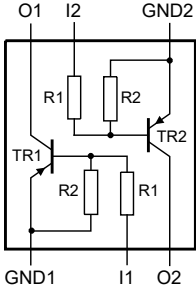
| Symbol                | Parameter                 | Conditions | Min  | Typ  | Max  | Unit       |
|-----------------------|---------------------------|------------|------|------|------|------------|
| <b>Per transistor</b> |                           |            |      |      |      |            |
| V <sub>CEO</sub>      | collector-emitter voltage | open base  | -    | -    | -50  | V          |
| I <sub>O</sub>        | output current            |            | -    | -    | -500 | mA         |
| R1                    | bias resistor 1 (input)   | [1]        | 1.54 | 2.2  | 2.86 | k $\Omega$ |
| R2/R1                 | bias resistor ratio       | [1]        | 4.1  | 4.55 | 5    |            |

[1] See section "Test information" for resistor calculation and test conditions.

50 V, 500 mA PNP/PNP Resistor-Equipped double Transistor (RET); R1 = 2.2 kΩ, R2 = 10 kΩ

5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description            | Simplified outline   | Graphic symbol  |
|-----|--------|------------------------|--|---|
| 1   | GND1   | GND (emitter) TR1      | <br>SC-74; TSOP6 (SOT457) | <br>aaa-019790 |
| 2   | I1     | input (base) TR1       |  |   |
| 3   | O2     | output (collector) TR2 |  |   |
| 4   | GND2   | GND (emitter) TR2      |  |   |
| 5   | I2     | input (base) TR2       |  |   |
| 6   | O1     | output (collector) TR1 |  |   |

6. Ordering information

Table 3. Ordering information

| Type number | Package      |  |         |
|-------------|--------------|--|---------|
|             | Name         | Description  | Version |
| PIMP32-Q    | SC-74; TSOP6 | plastic, surface-mounted package (SC-74; TSOP6); 6 leads | SOT457  |

7. Marking

Table 4. Marking codes

| Type number | Marking code |
|-------------|--------------|
| PIMP32-Q    | 4J           |

8. Limiting values

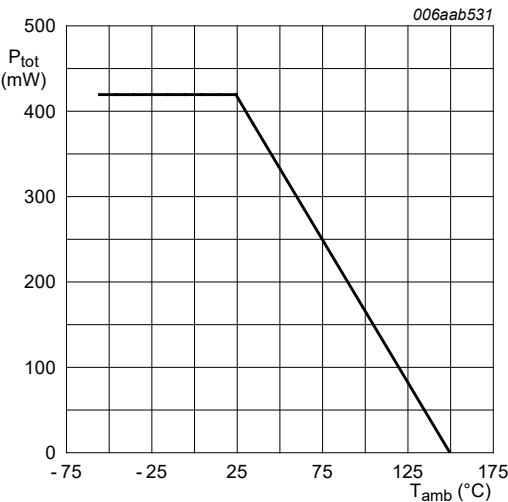
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol           | Parameter                 | Conditions               |     | Min | Max  | Unit |
|------------------|---------------------------|--------------------------|-----|-----|------|------|
| Per transistor   |                           |                          |     |     |      |      |
| V <sub>CBO</sub> | collector-base voltage    | open emitter             |     | -   | -50  | V    |
| V <sub>CEO</sub> | collector-emitter voltage | open base                |     | -   | -50  | V    |
| V <sub>EBO</sub> | emitter-base voltage      | open collector           |     | -   | -5   | V    |
| V <sub>I</sub>   | input voltage             |                          |     | -12 | 5    | V    |
| I <sub>O</sub>   | output current            |                          |     | -   | -500 | mA   |
| P <sub>tot</sub> | total power dissipation   | T <sub>amb</sub> ≤ 25 °C | [1] | -   | 290  | mW   |
| Per device       |                           |                          |     |     |      |      |
| P <sub>tot</sub> | total power dissipation   | T <sub>amb</sub> ≤ 25 °C | [1] | -   | 420  | mW   |
| T <sub>j</sub>   | junction temperature      |                          |     | -   | 150  | °C   |
| T <sub>amb</sub> | ambient temperature       |                          |     | -55 | 150  | °C   |
| T <sub>stg</sub> | storage temperature       |                          |     | -65 | 150  | °C   |

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided, 35 μm copper, tin-plated and standard footprint.

50 V, 500 mA PNP/PNP Resistor-Equipped double Transistor (RET); R1 = 2.2 kΩ, R2 = 10 kΩ



FR4 PCB, single-sided, 35 μm copper, tin-plated and standard footprint

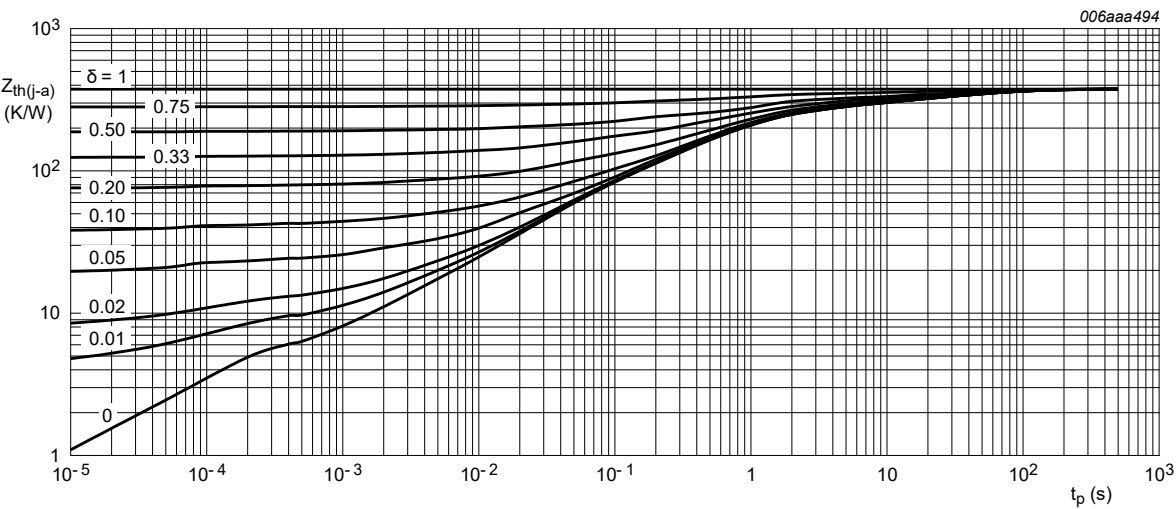
Fig. 1. Per device: Power derating curve

9. Thermal characteristics

Table 6. Thermal characteristics

| Symbol                | Parameter  | Conditions  |     | Min | Typ | Max | Unit |
|-----------------------|--|-------------|-----|-----|-----|-----|------|
| <b>Per transistor</b> |  |             |     |     |     |     |      |
| R <sub>th(j-a)</sub>  | thermal resistance from junction to ambient      | in free air | [1] | -   | -   | 432 | K/W  |
| R <sub>th(j-sp)</sub> | thermal resistance from junction to solder point |             |     | -   | -   | 105 | K/W  |
| <b>Per device</b>     |  |             |     |     |     |     |      |
| R <sub>th(j-a)</sub>  | thermal resistance from junction to ambient      | in free air | [1] | -   | -   | 298 | K/W  |

[1] Device mounted on an FR4 PCB, single-sided, 35 μm copper, tin-plated and standard footprint.



FR4 PCB, single-sided, 35μm copper, tin-plated and standard footprint

Fig. 2. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

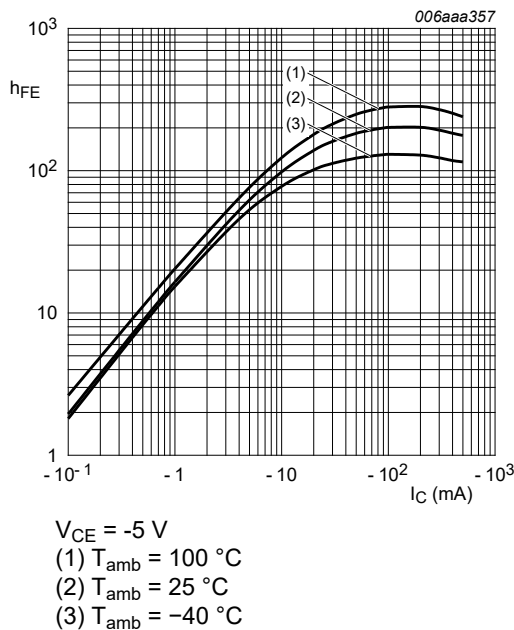
## 10. Characteristics

Table 7. Characteristics

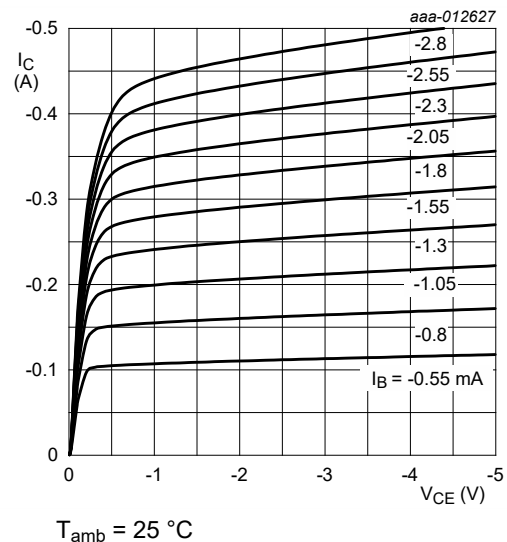
| Symbol                | Parameter                            | Conditions   | Min  | Typ   | Max   | Unit          |
|-----------------------|--------------------------------------|--|------|-------|-------|---------------|
| <b>Per transistor</b> |                                      |  |      |       |       |               |
| $V_{(BR)CBO}$         | collector-base breakdown voltage     | $I_C = -100\ \mu\text{A}$ ; $I_E = 0\ \text{A}$ ; $T_{\text{amb}} = 25\ ^\circ\text{C}$  | -50  | -     | -     | V             |
| $V_{(BR)CEO}$         | collector-emitter breakdown voltage  | $I_C = -10\ \text{mA}$ ; $I_B = 0\ \text{A}$ ; $T_{\text{amb}} = 25\ ^\circ\text{C}$   | -50  | -     | -     | V             |
| $I_{CBO}$             | collector-base cut-off current       | $V_{CB} = -50\ \text{V}$ ; $I_E = 0\ \text{A}$ ; $T_{\text{amb}} = 25\ ^\circ\text{C}$   | -    | -     | -100  | nA            |
| $I_{CEO}$             | collector-emitter cut-off current    | $V_{CE} = -50\ \text{V}$ ; $I_B = 0\ \text{A}$ ; $T_{\text{amb}} = 25\ ^\circ\text{C}$   | -    | -     | -0.5  | $\mu\text{A}$ |
| $I_{EBO}$             | emitter-base cut-off current         | $V_{EB} = -5\ \text{V}$ ; $I_C = 0\ \text{A}$ ; $T_{\text{amb}} = 25\ ^\circ\text{C}$  | -    | -     | -0.65 | mA            |
| $h_{FE}$              | DC current gain                      | $V_{CE} = -5\ \text{V}$ ; $I_C = -50\ \text{mA}$ ; $T_{\text{amb}} = 25\ ^\circ\text{C}$   | 70   | -     | -     |               |
| $V_{CEsat}$           | collector-emitter saturation voltage | $I_C = -50\ \text{mA}$ ; $I_B = -2.5\ \text{mA}$ ; $T_{\text{amb}} = 25\ ^\circ\text{C}$   | -    | -     | -100  | mV            |
| $V_{I(off)}$          | off-state input voltage              | $V_{CE} = -5\ \text{V}$ ; $I_C = -100\ \mu\text{A}$ ; $T_{\text{amb}} = 25\ ^\circ\text{C}$  | -0.4 | -0.65 | -1    | V             |
| $V_{I(on)}$           | on-state input voltage               | $V_{CE} = -0.3\ \text{V}$ ; $I_C = -20\ \text{mA}$ ; $T_{\text{amb}} = 25\ ^\circ\text{C}$   | -0.5 | -0.95 | -1.4  | V             |
| R1                    | bias resistor 1 (input)              | [1]  | 1.54 | 2.2   | 2.86  | kΩ            |
| R2/R1                 | bias resistor ratio                  | [1]  | 4.1  | 4.55  | 5     |               |
| $C_c$                 | collector capacitance                | $V_{CB} = -10\ \text{V}$ ; $I_E = 0\ \text{A}$ ; $i_e = 0\ \text{A}$ ; $f = 1\ \text{MHz}$ ; $T_{\text{amb}} = 25\ ^\circ\text{C}$ | -    | 11    | -     | pF            |
| $f_T$                 | transition frequency                 | $V_{CE} = -5\ \text{V}$ ; $I_C = -50\ \text{mA}$ ; $f = 100\ \text{MHz}$ ; $T_{\text{amb}} = 25\ ^\circ\text{C}$                   | [2]  | 140   | -     | MHz           |

[1] See section "Test information" for resistor calculation and test conditions.

[2] Characteristics of built-in transistor



**Fig. 3. DC current gain as a function of collector current; typical values**



**Fig. 4. Collector current as a function of collector-emitter voltage, typical values**

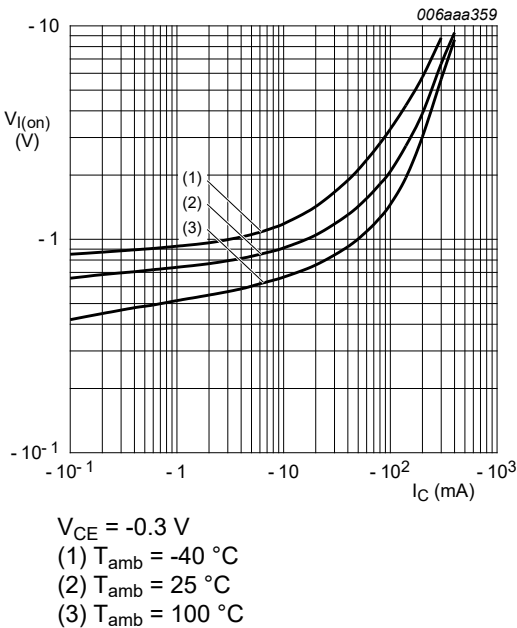


Fig. 5. On-state input voltage as a function of collector current; typical values

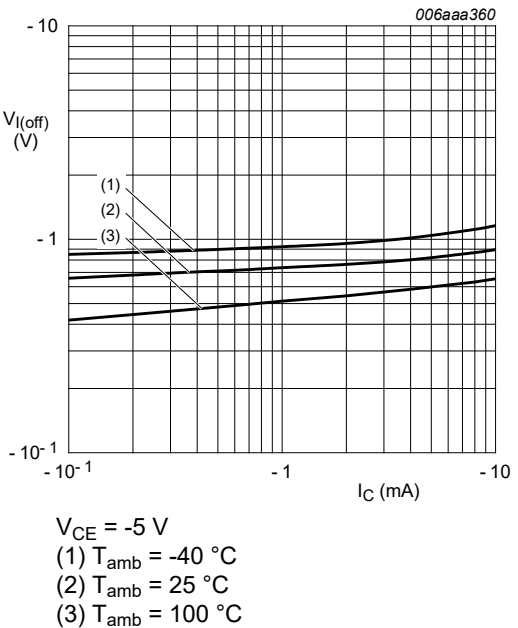


Fig. 6. Off-state input voltage as a function of collector current; typical values

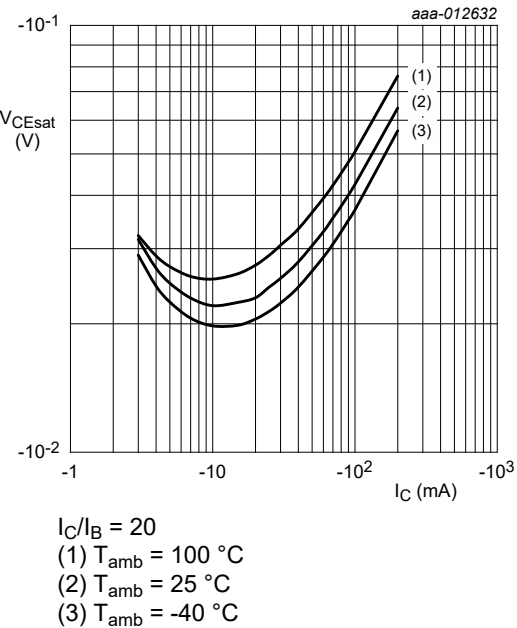


Fig. 7. Collector-emitter saturation voltage as a function of collector current; typical values

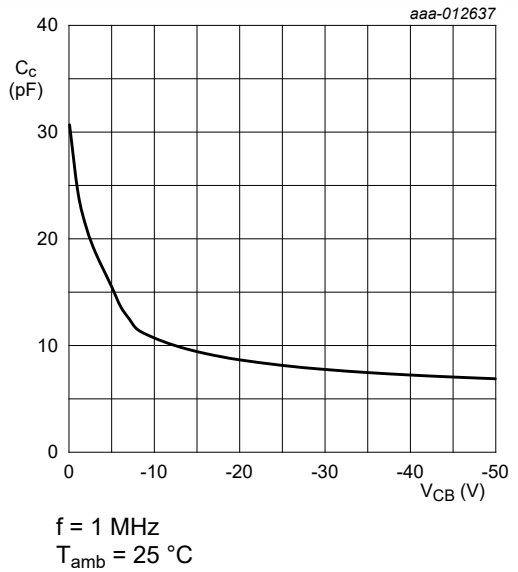
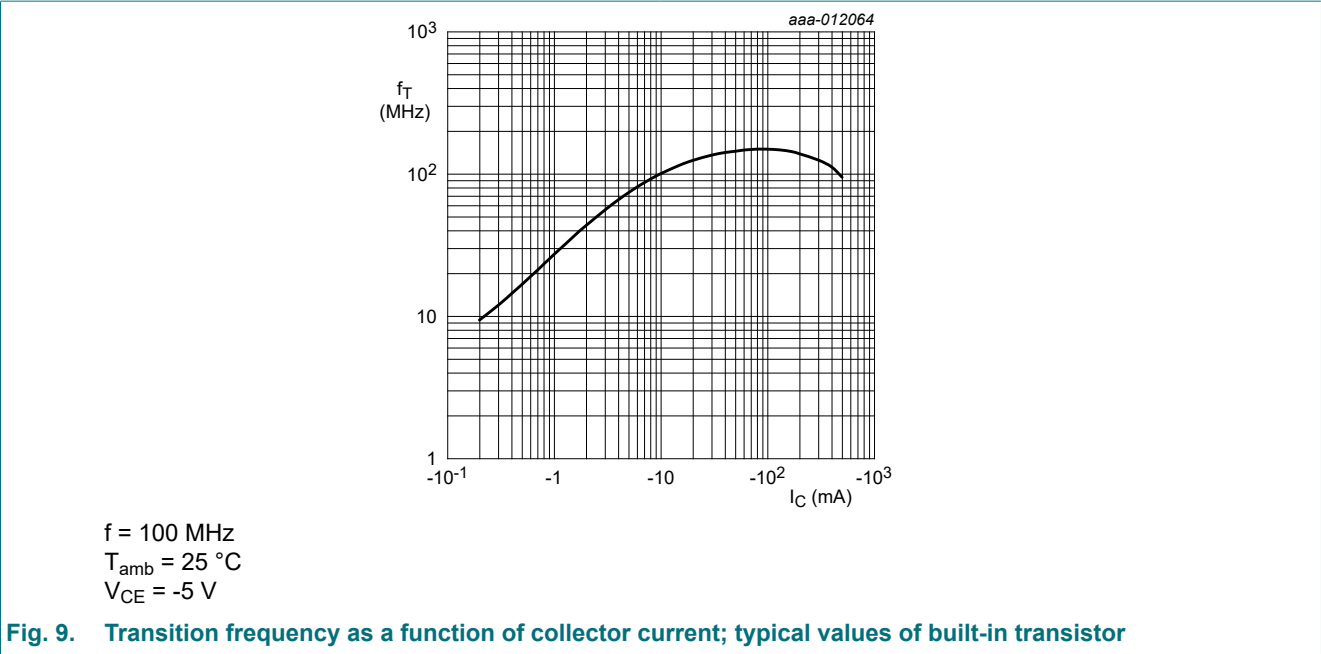


Fig. 8. Collector capacitance as a function of collector-base voltage; typical values

50 V, 500 mA PNP/PNP Resistor-Equipped double Transistor (RET); R1 = 2.2 kΩ, R2 = 10 kΩ



11. Test information

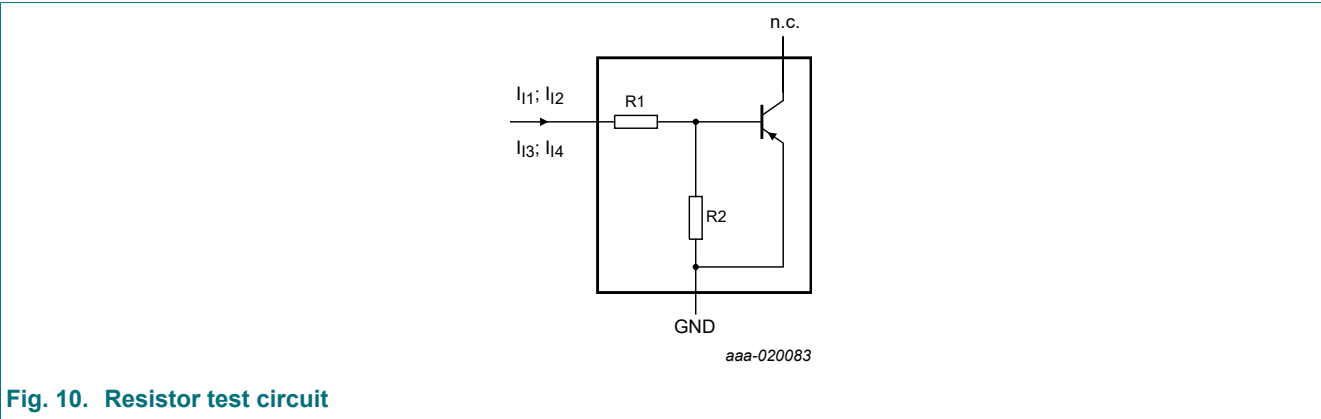
Resistor calculation

- Calculation of bias resistor 1 (R1)

$$R1 = \frac{V(I12) - V(I11)}{I12 - I11}$$

- Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I14) - V(I13)}{R1 \cdot (I14 - I13)} - 1$$



Resistor test conditions

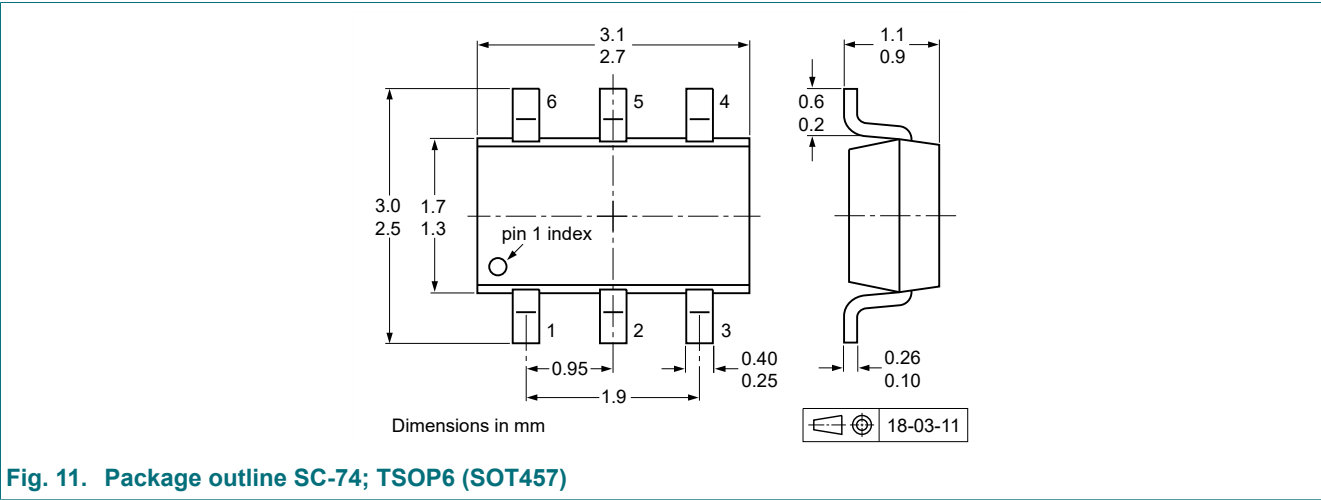
Table 8. Resistor test conditions

| R1 (kΩ) | R2 (kΩ) | Test conditions |         |         |         |
|---------|---------|-----------------|---------|---------|---------|
|         |         | I11             | I12     | I13     | I14     |
| 2.2     | 10      | -0.7 mA         | -0.8 mA | 0.45 mA | 0.55 mA |

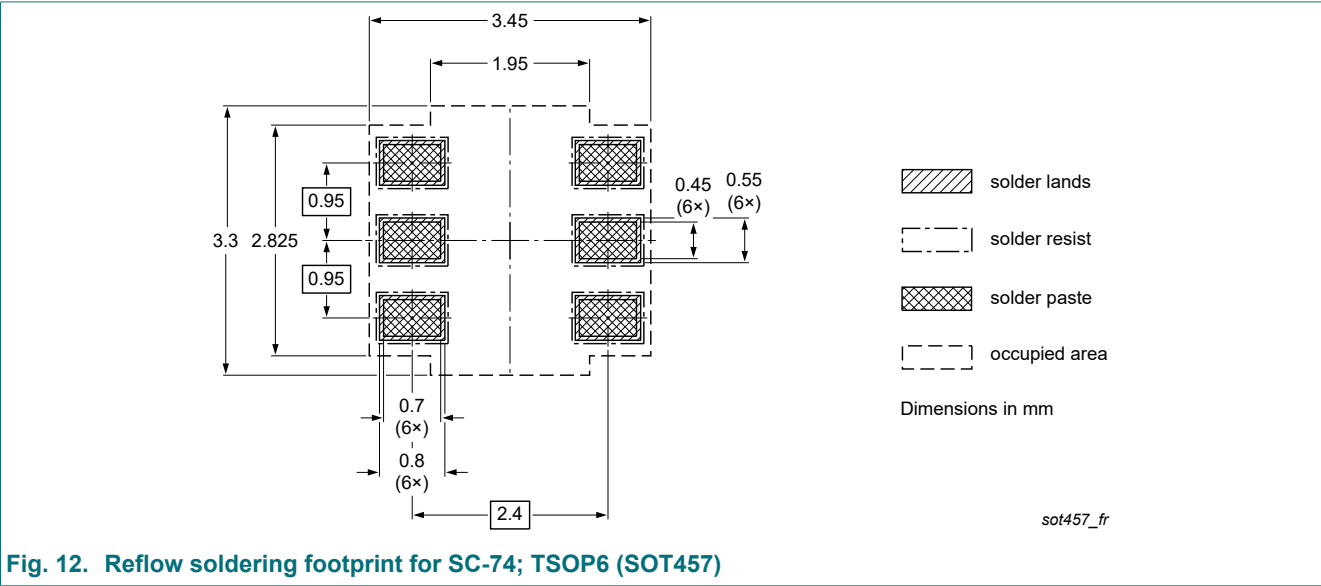
Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline



13. Soldering





50 V, 500 mA PNP/PNP Resistor-Equipped double Transistor (RET); R1 = 2.2 kΩ, R2 = 10 kΩ

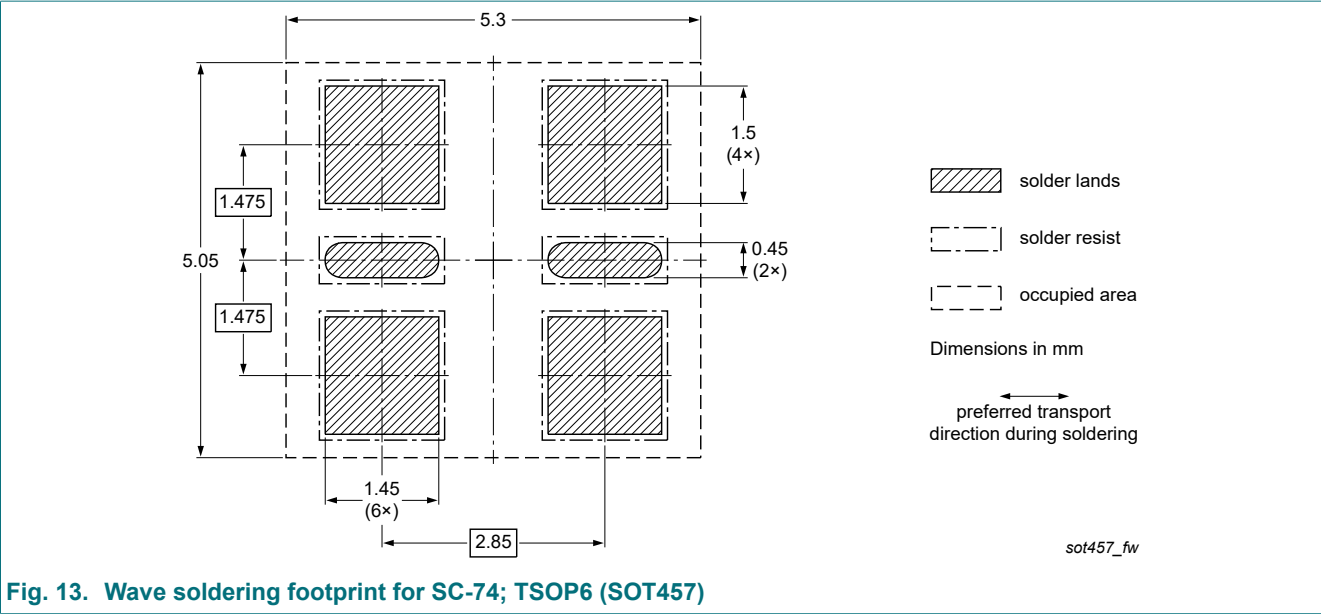


Fig. 13. Wave soldering footprint for SC-74; TSOP6 (SOT457)

50 V, 500 mA PNP/PNP Resistor-Equipped double Transistor (RET); R1 = 2.2 kΩ, R2 = 10 kΩ

14. Revision history

Table 9. Revision history

| Data sheet ID | Release date | Data sheet status  | Change notice | Supersedes |
|---------------|--------------|--------------------|---------------|------------|
| PIMP32-Q v.1  | 20220216     | Product data sheet | -             | -          |

## 15. Legal information

### Data sheet status

| Document status<br>[1][2]      | Product status [3] | Definition  |
|--------------------------------|--------------------|---|
| Objective [short] data sheet   | Development        | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification      | This document contains data from the preliminary specification.                       |
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- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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